

## N-Channel 30-V (D-S) MOSFET

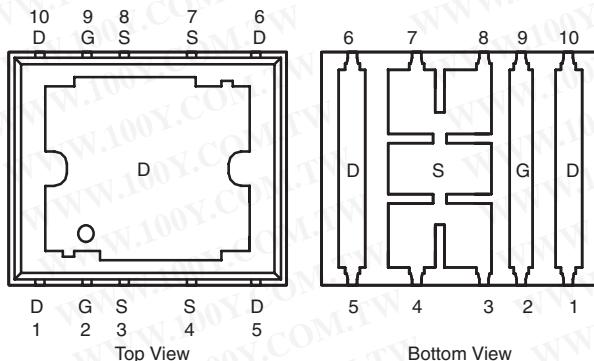
### PRODUCT SUMMARY

$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ ) <sup>e</sup>	$I_D$ (A)		$Q_g$ (Typ.)
		Silicon Limit	Package Limit	
30	0.0017 at $V_{GS} = 10$ V	202	60	75 nC
	0.0021 at $V_{GS} = 4.5$ V	187	60	

Package Drawing

[www.vishay.com/doc?72945](http://www.vishay.com/doc?72945)

PolarPAK



Top surface is connected to pins 1, 5, 6, and 10

Ordering Information: SiE806DF-T1-E3 (Lead (Pb)-free)  
 SiE806DF-T1-GE3 (Lead (Pb)-free and Halogen-free)

### FEATURES

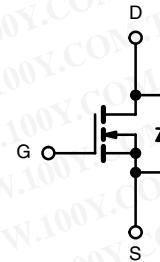
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Gen II Power MOSFET
- Ultra Low Thermal Resistance Using Top-Exposed PolarPAK® Package for Double-Sided Cooling
- Leadframe-Based New Encapsulated Package
  - Die Not Exposed
  - Same Layout Regardless of Die Size
- Low  $Q_{gd}/Q_{gs}$  Ratio Helps Prevent Shoot-Through
- 100 %  $R_g$  and UIS Tested
- Compliant to RoHS directive 2002/95/EC



RoHS  
COMPLIANT  
HALOGEN  
**FREE**  
Available

### APPLICATIONS

- VRM
- DC/DC Conversion: Low-Side
- Synchronous Rectification



N-Channel MOSFET

For Related Documents  
[www.vishay.com/pgg?73740](http://www.vishay.com/pgg?73740)

### ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	
Continuous Drain Current ( $T_J = 150$ °C)	$I_D$	202 (Silicon Limit) 60 <sup>a</sup> (Package Limit)	A
		60 <sup>a</sup>	
		41.3 <sup>b, c</sup>	
		33 <sup>b, c</sup>	
Pulsed Drain Current	$I_{DM}$	100	
Continuous Source-Drain Diode Current	$I_S$	60 <sup>a</sup>	
		4.3 <sup>b, c</sup>	
Single Pulse Avalanche Current	$I_{AS}$	50	
Avalanche Energy	$E_{AS}$	125	mJ
Maximum Power Dissipation	$P_D$	125	W
		80	
		5.2 <sup>b, c</sup>	
		3.3 <sup>b, c</sup>	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	°C
Soldering Recommendations (Peak Temperature) <sup>d, e</sup>		260	

Notes:

- Package limited is 60 A.
- Surface Mounted on 1" x 1" FR4 board.
- t = 10 s.
- See Solder Profile ([www.vishay.com/doc?73257](http://www.vishay.com/doc?73257)). The PolarPAK is a leadless package. The end of the lead terminal is exposed copper not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

### THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a, b</sup>	$t \leq 10 \text{ s}$	$R_{thJA}$	20	24	
Maximum Junction-to-Case (Drain Top)		$R_{thJC}$ (Drain)	0.8	1	
Maximum Junction-to-Case (Source) <sup>a, c</sup>	Steady State	$R_{thJFC}$ (Source)	2.2	2.7	°C/W

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. Maximum under Steady State conditions is 68 °C/W.
- c. Measured at source pin (on the side of the package).

### SPECIFICATIONS $T_J = 25 \text{ }^{\circ}\text{C}$ , unless otherwise noted

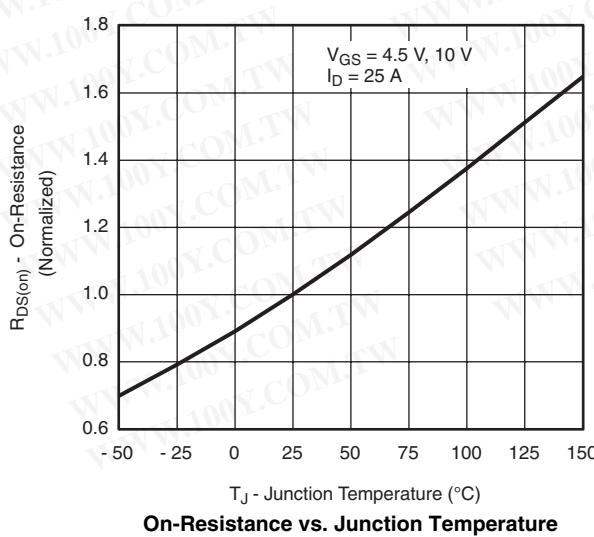
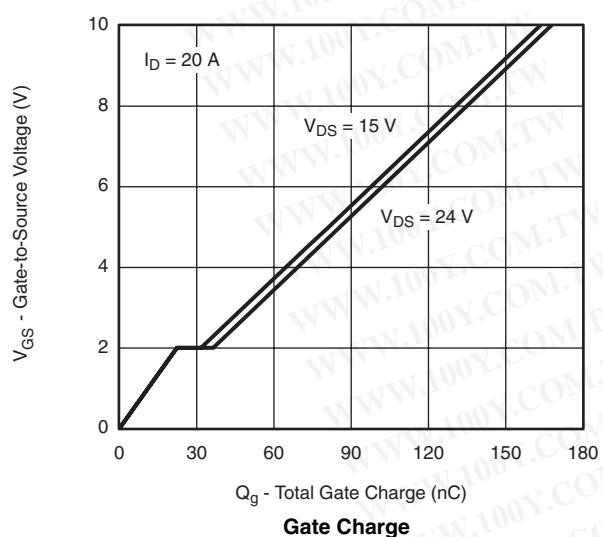
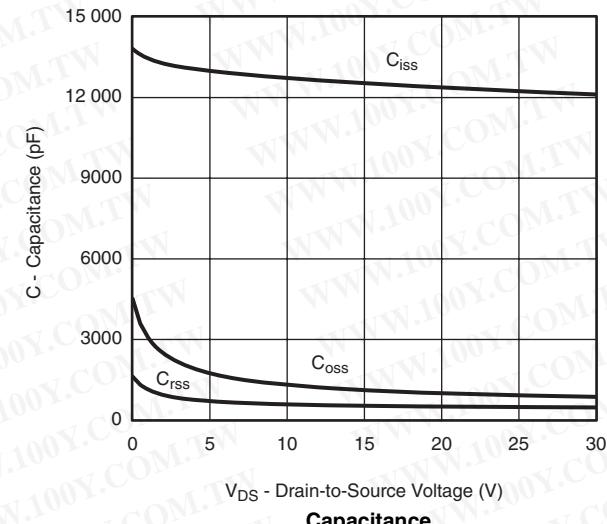
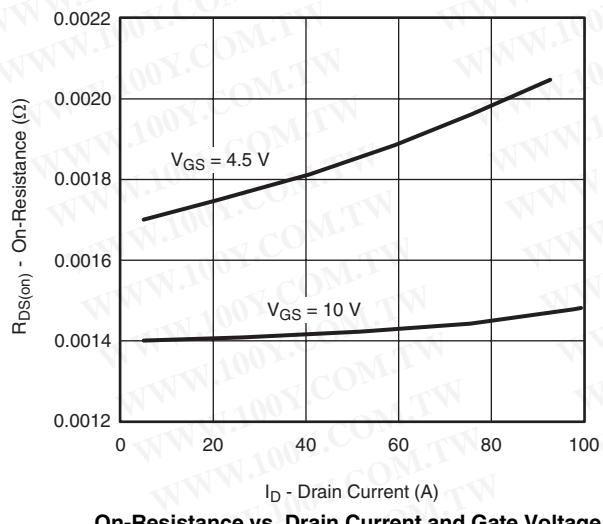
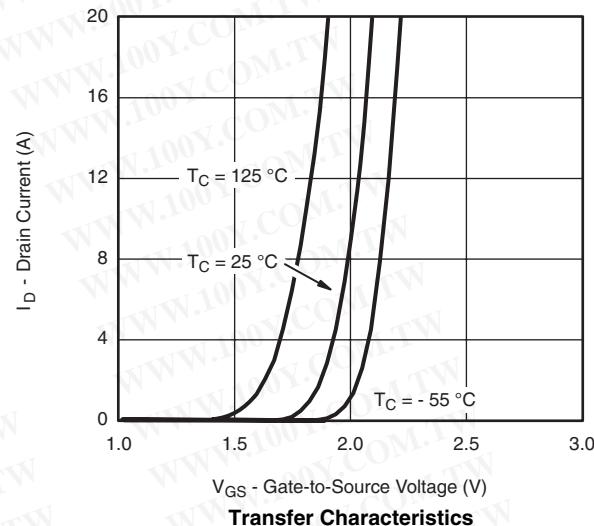
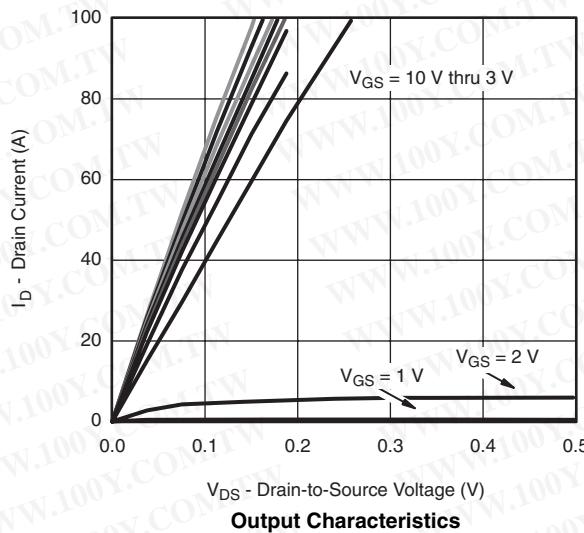
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	30			V
$V_{DS}$ Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250 \mu\text{A}$		29		
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 5.1		mV/°C
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	0.6	1.3	2	V
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55 \text{ }^{\circ}\text{C}$			10	μA
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \geq 5 \text{ V}, V_{GS} = 10 \text{ V}$	25			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$		0.0014	0.0017	
		$V_{GS} = 4.5 \text{ V}, I_D = 25 \text{ A}$		0.0017	0.0021	Ω
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_D = 25 \text{ A}$		130		S
<b>Dynamic<sup>b</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		13000		
Output Capacitance	$C_{oss}$			1150		
Reverse Transfer Capacitance	$C_{rss}$			550		pF
Total Gate Charge	$Q_g$	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		165	250	
				75	115	
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		23		nC
Gate-Drain Charge	$Q_{gd}$			9.5		
Gate Resistance	$R_g$	$f = 1 \text{ MHz}$		0.9	1.35	Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 15 \text{ V}, R_L = 1.5 \Omega$		125	190	
Rise Time	$t_r$	$I_D \geq 10 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		160	240	
Turn-Off Delay Time	$t_{d(off)}$			85	130	
Fall Time	$t_f$			15	25	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 15 \text{ V}, R_L = 1.5 \Omega$		20	30	ns
Rise Time	$t_r$	$I_D \geq 10 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		50	75	
Turn-Off Delay Time	$t_{d(off)}$			85	130	
Fall Time	$t_f$			10	15	
<b>Drain-Source Body Diode Characteristics</b>						
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25 \text{ }^{\circ}\text{C}$			60	
Pulse Diode Forward Current <sup>a</sup>	$I_{SM}$				100	A
Body Diode Voltage	$V_{SD}$	$I_S = 10 \text{ A}$		0.9	1.2	V
Body Diode Reverse Recovery Time	$t_{rr}$			52	80	ns
Body Diode Reverse Recovery Charge	$Q_{rr}$			55	105	nC
Reverse Recovery Fall Time	$t_a$			25		
Reverse Recovery Rise Time	$t_b$			27		ns

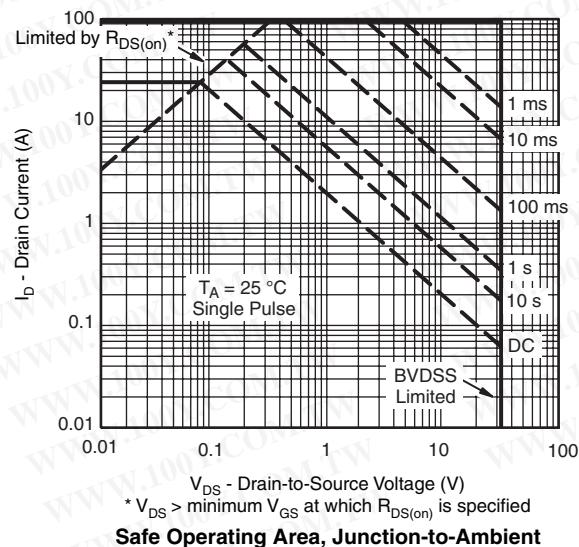
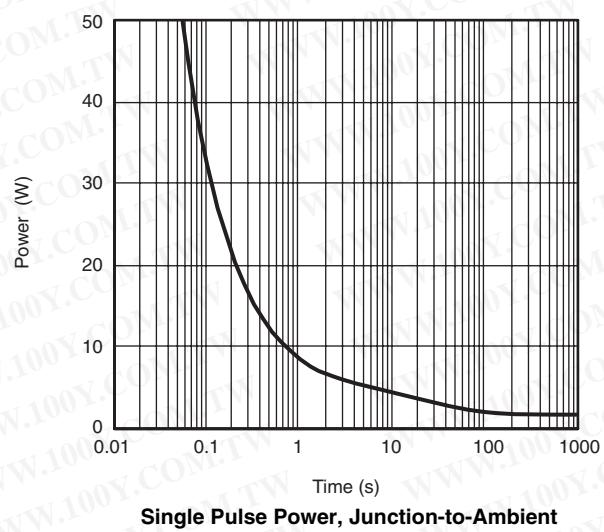
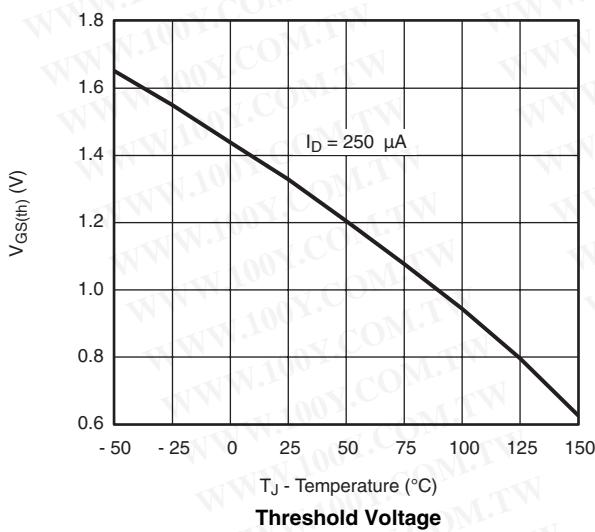
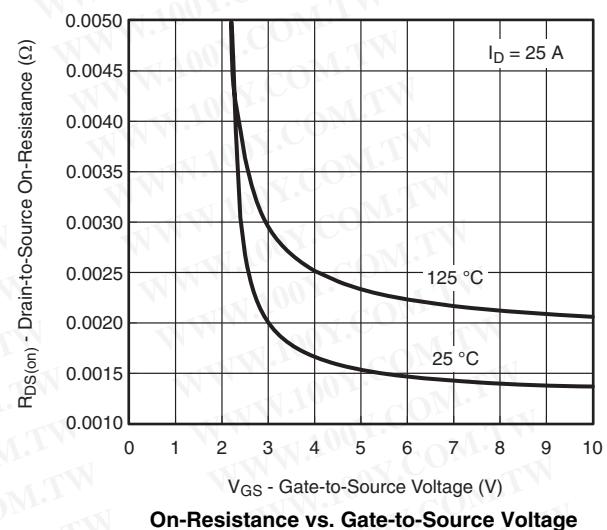
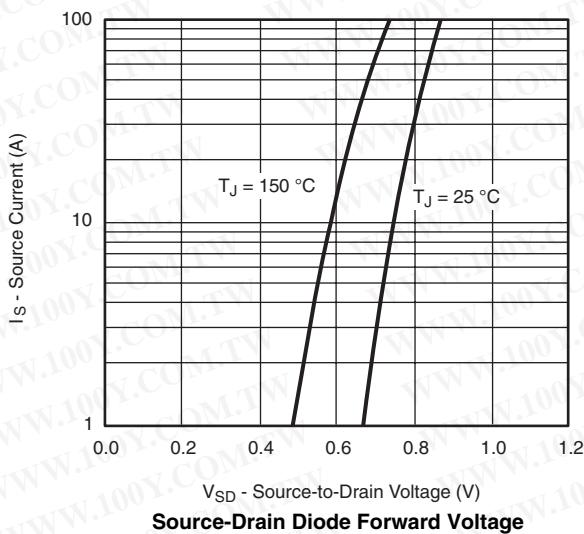
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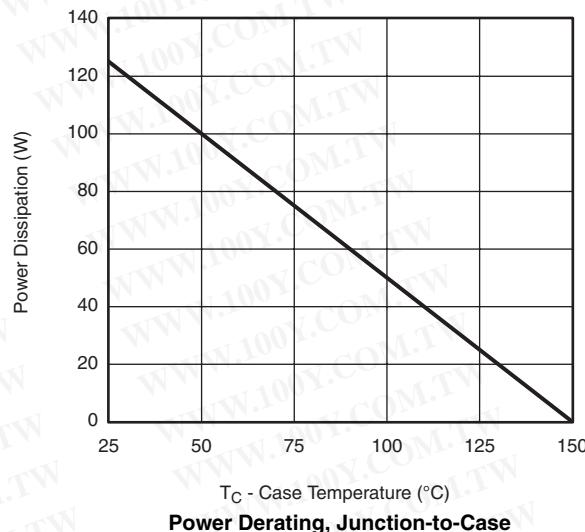
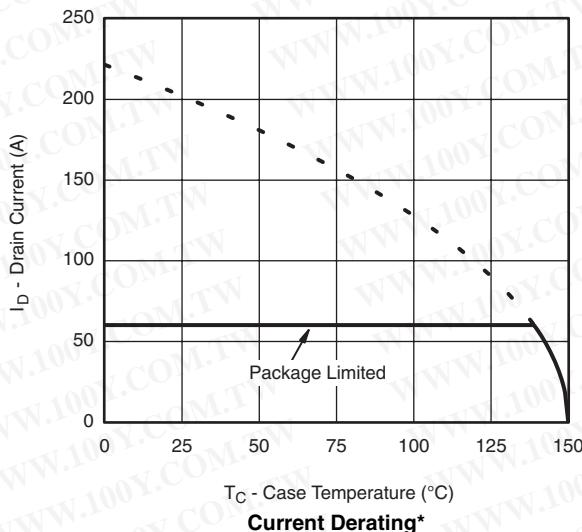
- a. Pulse test; pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2 \%$ .
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

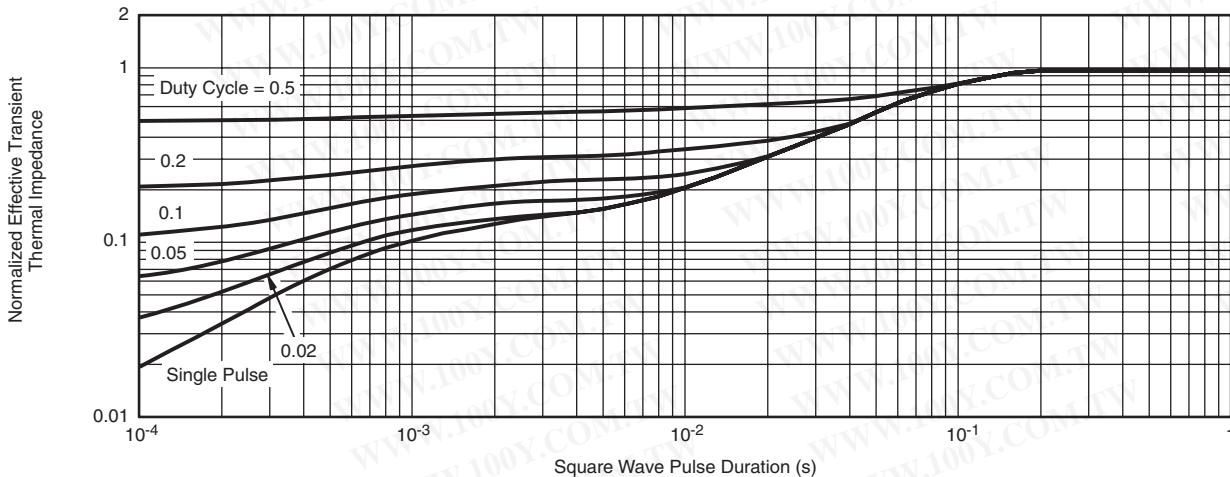
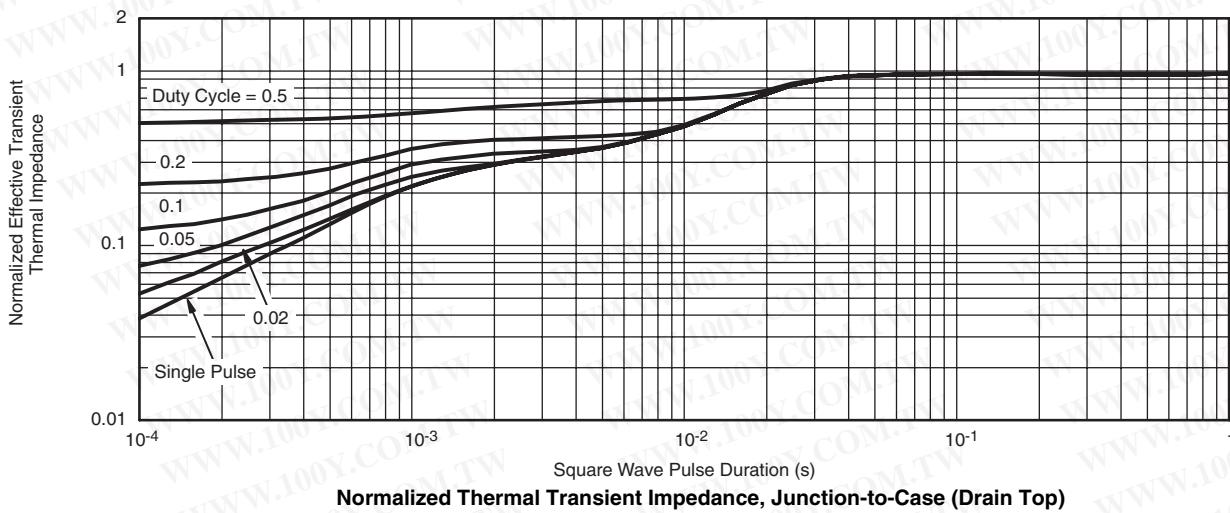
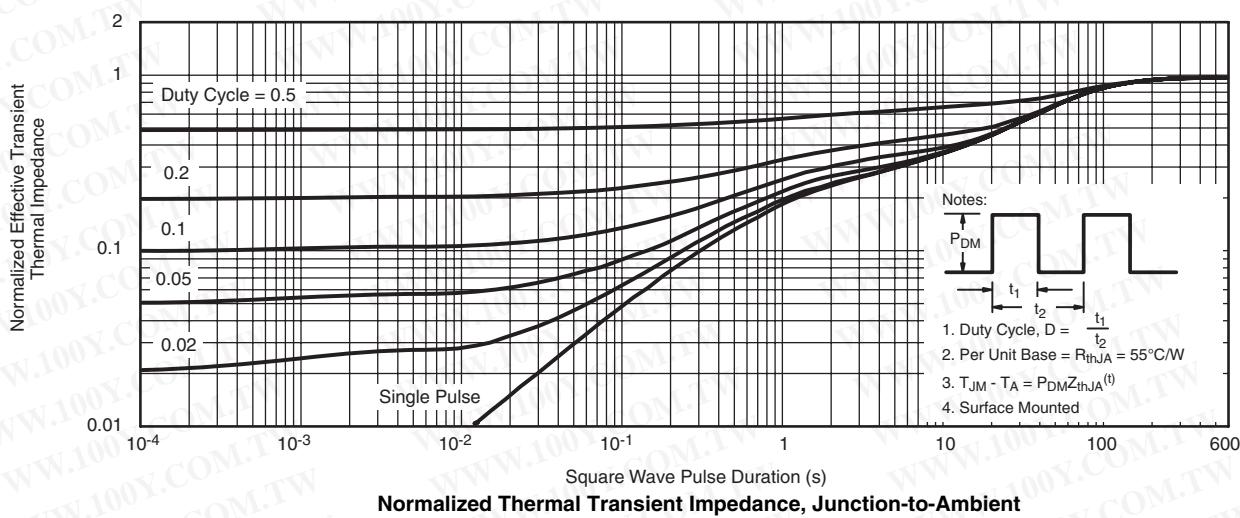


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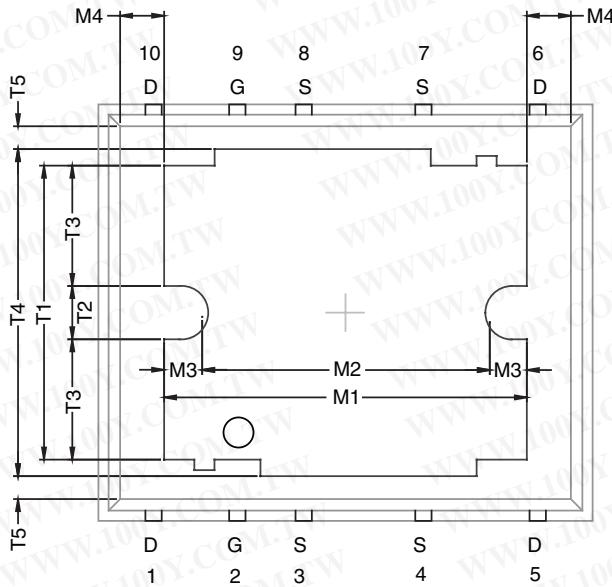
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\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

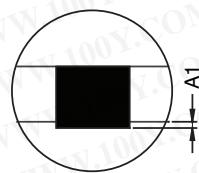
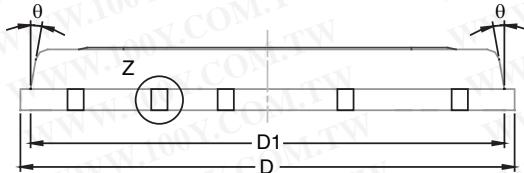
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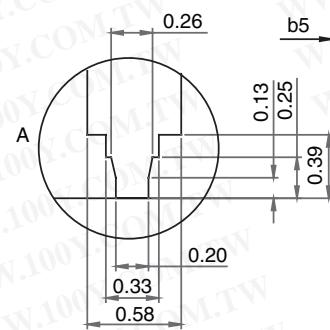
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**POLARPAK™ OPTION L**


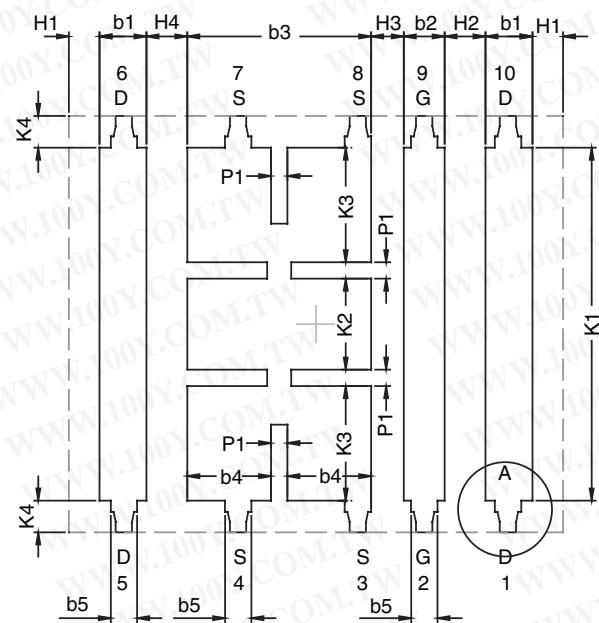
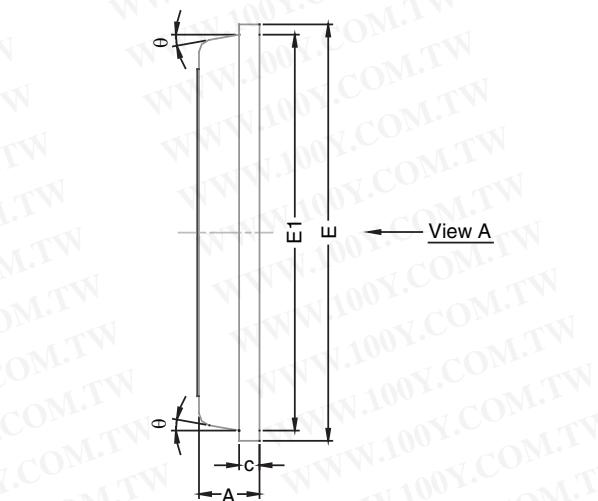
(Top View)



DETAIL Z



Product datasheet/information page contain links to applicable package drawing.


 View A  
 (Bottom View)

# Package Information

Vishay Siliconix



DIM	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.75	0.80	0.85	0.030	0.031	0.033
A1	0.00	-	0.05	0.000	-	0.002
b1	0.48	0.58	0.68	0.019	0.023	0.027
b2	0.41	0.51	0.61	0.016	0.020	0.024
b3	2.19	2.29	2.39	0.086	0.090	0.094
b4	0.89	1.04	1.19	0.035	0.041	0.047
b5	0.23	0.33	0.43	0.009	0.013	0.017
c	0.20	0.25	0.30	0.008	0.010	0.012
D	6.00	6.15	6.30	0.236	0.242	0.248
D1	5.74	5.89	6.04	0.226	0.232	0.238
E	5.01	5.16	5.31	0.197	0.203	0.209
E1	4.75	4.90	5.05	0.187	0.193	0.199
H1	0.23	-	-	0.009	-	-
H2	0.45	-	0.56	0.018	-	0.022
H3	0.31	0.41	0.51	0.012	0.016	0.020
H4	0.45	-	0.56	0.018	-	0.022
K1	4.22	4.37	4.52	0.166	0.172	0.178
K2	1.08	1.13	1.18	0.043	0.044	0.046
K3	1.37	-	-	0.054	-	-
K4	0.24	-	-	0.009	-	-
M1	4.30	4.50	4.70	0.169	0.177	0.185
M2	3.43	3.58	3.73	0.135	0.141	0.147
M3	0.22	-	-	0.009	-	-
M4	0.05	-	-	0.002	-	-
P1	0.15	0.20	0.25	0.006	0.008	0.010
T1	3.48	3.64	4.10	0.137	0.143	0.161
T2	0.56	0.76	0.95	0.022	0.030	0.037
T3	1.20	-	-	0.047	-	-
T4	3.90	-	-	0.153	-	-
T5	0	0.18	0.36	0.000	0.007	0.014
$\theta$	0°	10°	12°	0°	10°	12°

ECN: T-08441-Rev. C, 11-Aug-08

DWG: 5946

## Notes

Millimeters govern over inches.

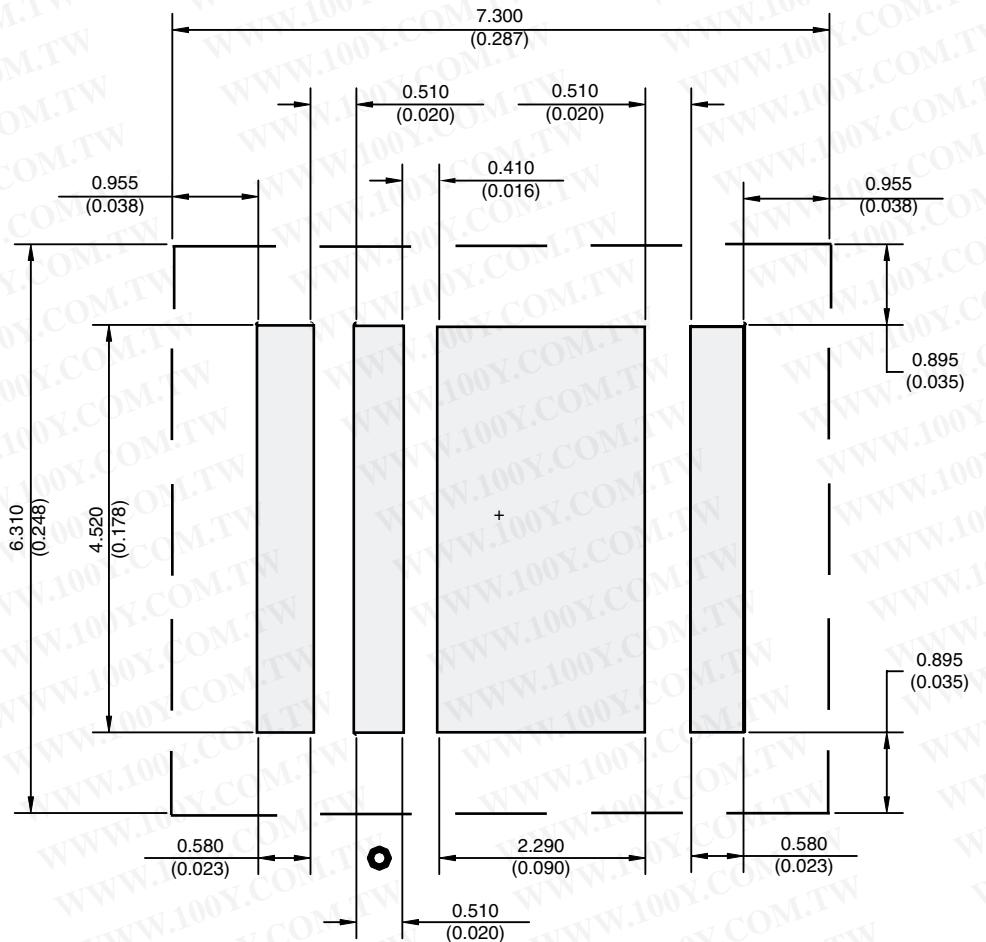
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# Application Note 826

Vishay Siliconix



## RECOMMENDED MINIMUM PADS FOR PolarPAK® Option L and S



Recommended Minimum for PolarPAK Option L and S

Dimensions in mm/(Inches)

No External Traces within Broken Lines

Dot indicates Gate Pin (Part Marking)

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